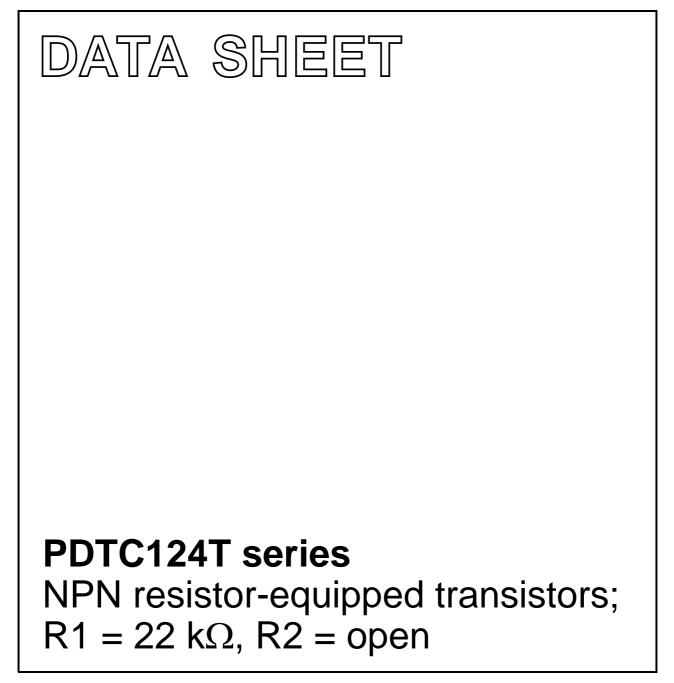
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 Apr 06 2004 Aug 13



## **PDTC124T series**

## FEATURES

- · Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

#### APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

**PRODUCT OVERVIEW** 

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	-	50	V
I <sub>O</sub>	output current (DC)	-	100	mA
R1	bias resistor	22	-	kΩ
R2	open	-	-	-

## DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

	PACKAGE				
TYPE NUMBER	PHILIPS	EIAJ	- MARKING CODE	PNP COMPLEMENT	
PDTC124TE	SOT416	SC-75	41	PDTA124TE	
PDTC124TEF	SOT490	SC-89	35	PDTA124TEF	
PDTC124TK	SOT346	SC-59	50	PDTA124TK	
PDTC124TM	SOT883	SC-101	DY	PDTA124TM	
PDTC124TS	SOT54 (TO-92)	SC-43	TC124T	PDTA124TS	
PDTC124TT	SOT23	_	*45 <sup>(1)</sup>	PDTA124TT	
PDTC124TU	SOT323	SC-70	*50 <sup>(1)</sup>	PDTA124TU	

#### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

# PDTC124T series

## SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTC124TS		1 2 3	base collector emitter		
	MAM361				
PDTC124TE		1	base		
PDTC124TEF PDTC124TK PDTC124TT PDTC124TU	3     1     3       1     2       Top view     MDB270	2 3	emitter collector		
PDTC124TM		1	base		
	2 1 Bottom view MHC507	2 3	emitter collector		

## PDTC124T series

## **ORDERING INFORMATION**

	PACKAGE			
TYPE NUMBER	NAME	DESCRIPTION	VERSION	
PDTC124TE	_	<ul> <li>plastic surface mounted package; 3 leads</li> </ul>		
PDTC124TEF	_	<ul> <li>plastic surface mounted package; 3 leads</li> </ul>		
PDTC124TK	_	<ul> <li>plastic surface mounted package; 3 leads</li> <li>SO<sup>-</sup></li> </ul>		
PDTC124TM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm		
PDTC124TS	<ul> <li>plastic single-ended leaded (through hole) package; 3 leads</li> </ul>		SOT54	
PDTC124TT	—	plastic surface mounted package; 3 leads	SOT23	
PDTC124TU	_	<ul> <li>plastic surface mounted package; 3 leads</li> <li>SOT</li> </ul>		

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	5	V
lo	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	-	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

## PDTC124T series

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

#### Notes

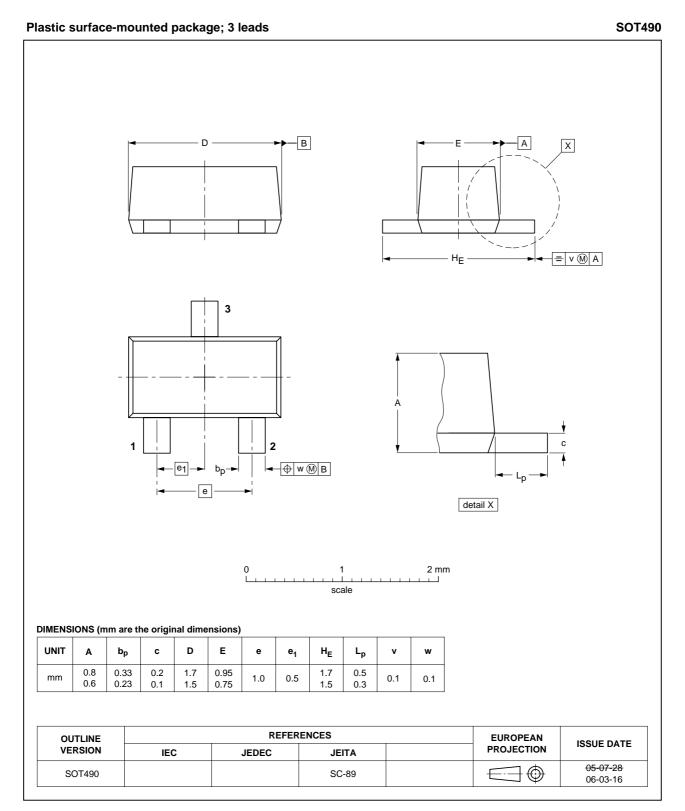
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- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

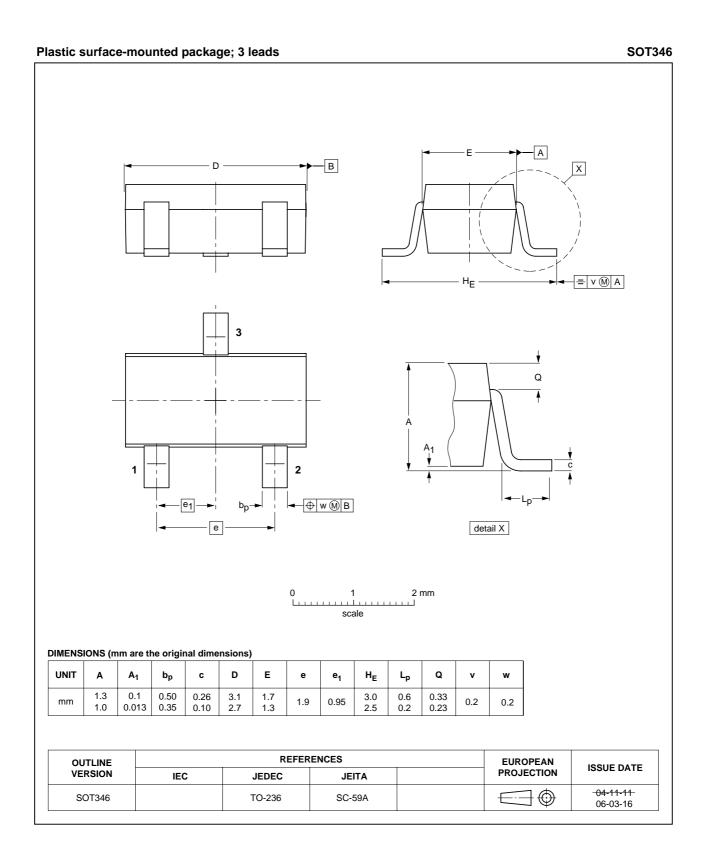
## CHARACTERISTICS

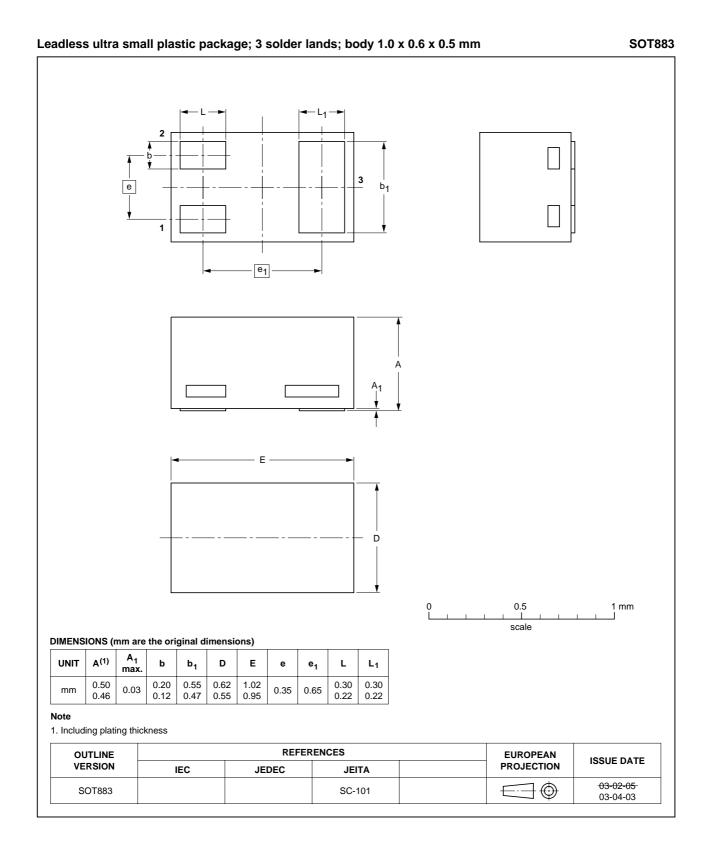
 $T_{amb}$  = 25 °C unless otherwise specified.

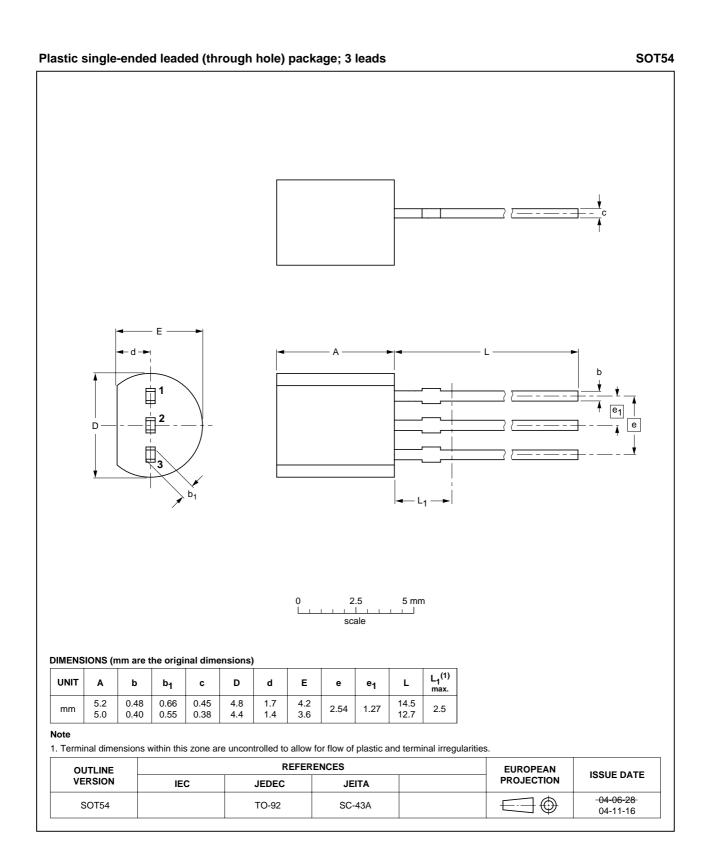
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A	-	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 mA	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	-	-	150	mV
R1	input resistor		15.4	22	28.6	kΩ
C <sub>c</sub>	collector capacitance	$I_{E} = i_{e} = 0 \text{ A}; \text{ V}_{CB} = 10 \text{ V};$ f = 1 MHz	-	-	2.5	pF

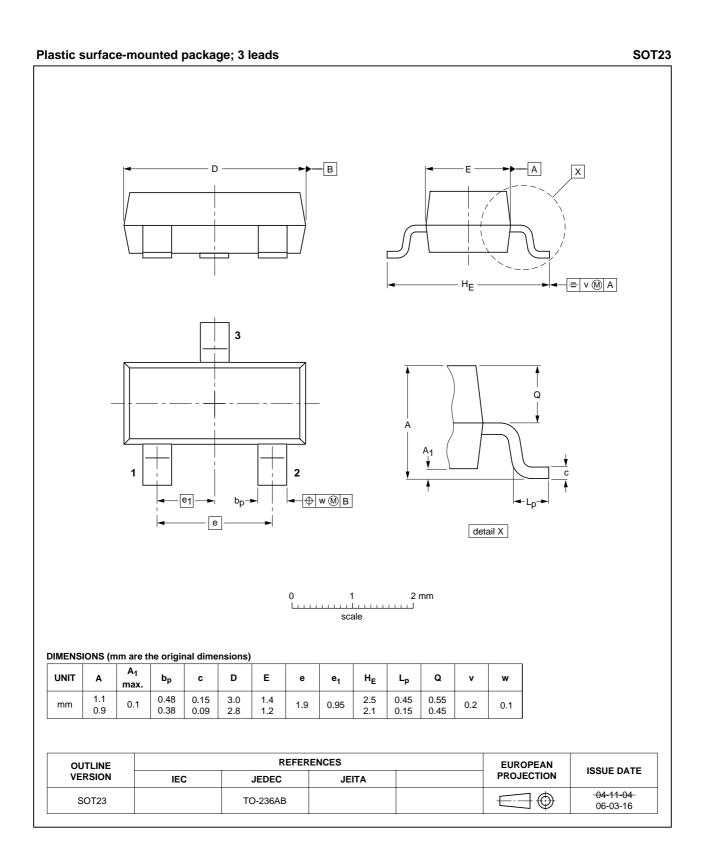
## PACKAGE OUTLINES

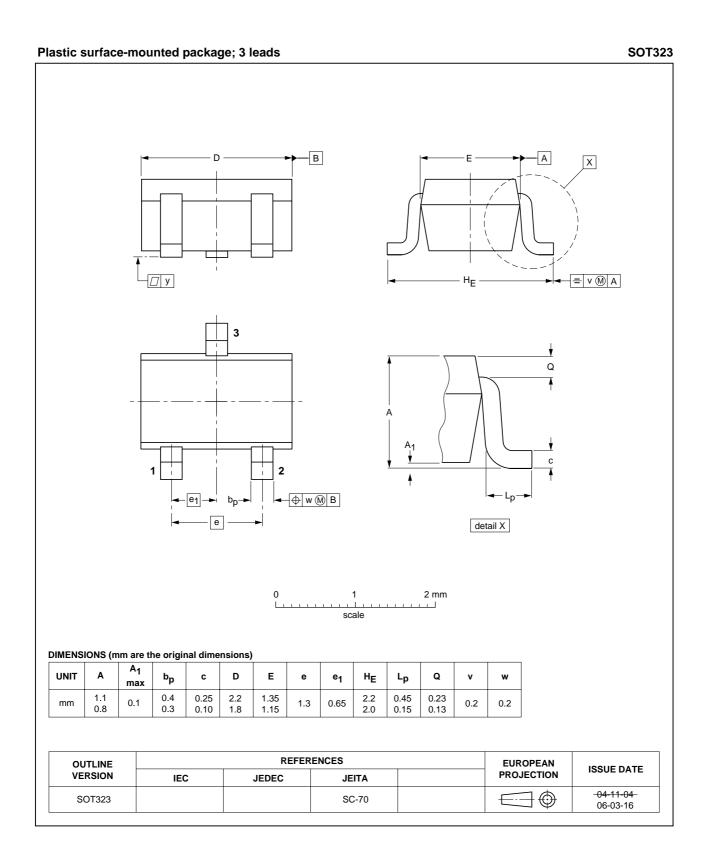


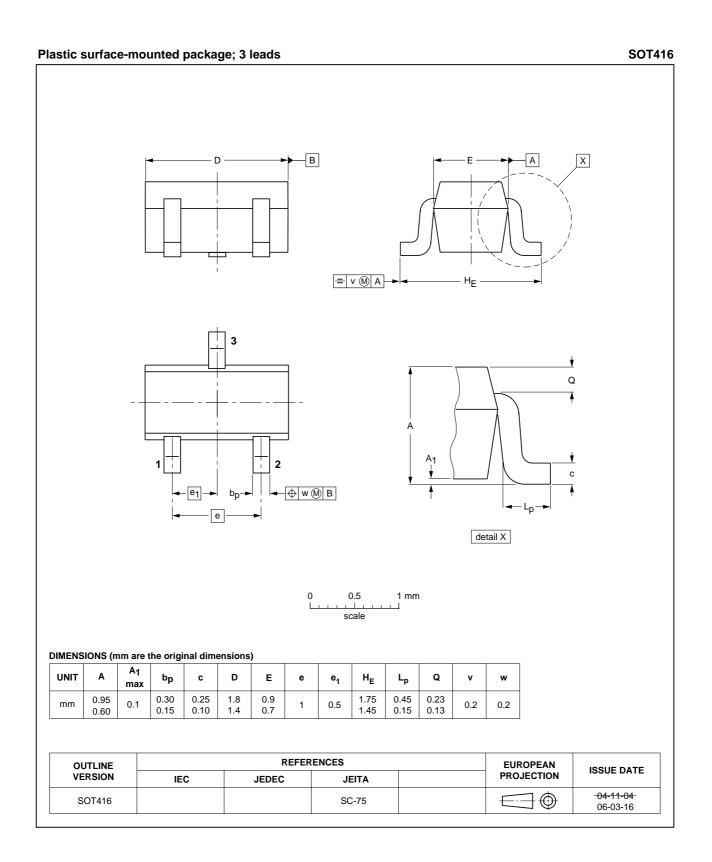












## PDTC124T series

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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# **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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